

## Fermi surfaces of the iron-based superconductor $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ observed by angle-resolved photoemission spectroscopy

Shin-ichiro IDETA<sup>\*1</sup>, Tepei YOSHIDA<sup>1,4</sup>, Ichiro NISHI<sup>1</sup>, Atsushi FUJIMORI<sup>1,4</sup>,  
Yoshinori KOTANI<sup>2</sup>, Masato KUBOTA<sup>2</sup>, Kanta ONO<sup>2</sup>, Masamichi NAKAJIMA<sup>1,4</sup>,  
Kunihiro KIHOU<sup>4,5</sup>, Yasuhide TOMIOKA<sup>4,5</sup>, C. H. LEE<sup>4,5</sup>, Akira IYO<sup>4,5</sup>, Hiroshi EISAKI<sup>4,5</sup>,  
Toshimitu ITO<sup>4,5</sup>, Yuji NAKAJIMA<sup>3</sup>, Takao SASAGAWA<sup>3</sup>,  
Shin-ichi UCHIDA<sup>1,4</sup>, Ryotaro ARITA<sup>4,5</sup>

<sup>1</sup>Department of Physics, University of Tokyo, Bunkyo-ku, Tokyo, 113-0022, Japan

<sup>2</sup>Photon Factory, Institute of Materials Structure Science, KEK, Tsukuba, Ibaraki 305-0801, Japan

<sup>3</sup>Materials and Structures Laboratory, Tokyo Institute of Technology,  
Meguro-ku, Tokyo 152-8550, Japan

<sup>4</sup>JST, Transformative Research-Project on Iron Pnictides (TRIP), Chiyoda, Tokyo 102-0075

<sup>5</sup>National Institute of Advanced Industrial Science and Technology, Tsukuba 305-8568, Japan

<sup>6</sup>Department of Applied Physics, University of Tokyo, Bunkyo-ku, Tokyo 113-8656

### Introduction

The electron-doped iron-based superconductor  $\text{Ba}(\text{Fe}_{1-x}\text{TM}_x)_2\text{As}_2$  (TM = Ni, Cu) shows superconductivity and the maximum superconducting transition temperature reaches  $\sim 18$  K at  $x \sim 0.05$  (TM = Ni) and  $\sim 2$  K at  $x \sim 0.044$  (TM = Cu) [1, 2]. In  $\text{Ba}(\text{Fe}_{1-x}\text{Ni}_x)_2\text{As}_2$  [ $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$ ], it is expected that the electron carrier concentration is twice (three times) as large as that of  $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ . In previous angle-resolved photoemission spectroscopy (ARPES) studies of  $\text{Ba}(\text{Fe}_{1-x}\text{Co}_x)_2\text{As}_2$ , the superconducting gaps [3] and the three-dimensional hole and electron Fermi surfaces (FSs) [4, 5] have been observed. Also, the shift of chemical potential and the number of hole and electron carriers have been estimated from the ARPES data, and interpreted by the rigid-band picture [5]. On the other hand, according to theoretical calculation, the doped  $d$  electrons due to the caused by impurity atoms such as Co, Ni and Cu are almost located within the muffin-tin sphere of the substituted site [6]. Therefore, the calculation is inconsistent with the rigid-band picture observed in the previous ARPES studies [5]. In this work, we have studied the electronic structure of  $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$  with Cu concentration  $x = 0.04, 0.06$  and  $0.08$ . Particularly, we focused on the photon-energy dependence of ARPES spectra.

### Experimental Condition

High-quality single crystals of non-superconducting  $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$  with  $x = 0.04, 0.06$ , and  $0.08$  were grown by self-flux method. ARPES measurements were carried out at Beamline 28A of Photon Factory (PF) using circularly-polarized light from  $h\nu = 34$  to  $88$  eV. A Scienta SES-2002 analyzer was used with the total energy resolution of  $\sim 15$  meV and the momentum resolution of  $\sim 0.02\pi/a$ . In-plane ( $k_x, k_y$ ) and out-of-plane electron momenta ( $k_z$ ) are expressed in units of  $\pi/a$  and  $2\pi/c$ , respectively, where  $a$  and  $c$  are the in-plane and out-of-

plane lattice constants. The crystals were cleaved *in situ* at  $T \sim 10$  K under an ultra-high vacuum of  $\sim 6 \times 10^{-11}$  Torr.

### Results and Discussion

Figure 1 shows the result of the mapping of the electron FSs for the optimally doped to overdoped Cu-Ba122 taken at  $T = 9$  K. We find that the hole FS along the  $\Gamma$ -Z direction disappears as a result of electron doping for all compositions. We have also found that the volume of the electron FS does not show a large difference between the different Cu concentrations. This result implies that the doped electron carriers by the Cu substitution are trapped around the impurity sites, and does not follow a simple rigid-band shift.

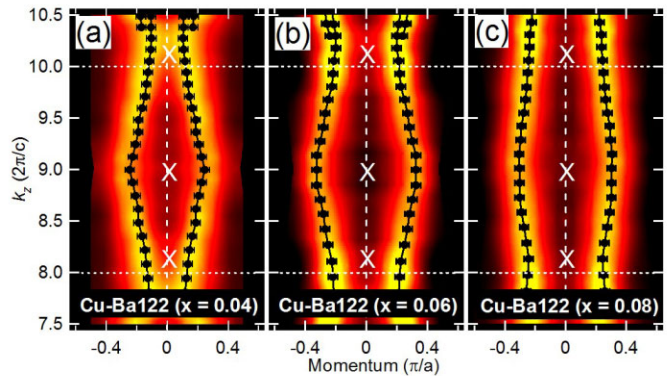


Figure 1: Three dimensionality of FS for nearly optimally doped (a) to overdoped  $\text{Ba}(\text{Fe}_{1-x}\text{Cu}_x)_2\text{As}_2$  (b, c).

### References

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- \* ideta@wyvern.phys.s.u-tokyo.ac.jp